

#### **Features**

- ► Free from secondary breakdown
- ► Low power drive requirement
- Ease of paralleling
- ► Low C<sub>ISS</sub> and fast switching speeds
- Excellent thermal stability
- ► Integral source-drain diode
- ► High input impedance and high gain

### **Applications**

- Motor controls
- Converters
- Amplifiers
- Switches
- Power supply circuits
- Drivers (relays, hammers, solenoids, lamps, memories, displays, bipolar transistors, etc.)

### **General Description**

The Supertex VN2224 is an enhancement-mode (normally-off) transistor that utilizes a vertical DMOS structure and Supertex's well-proven silicon-gate manufacturing process. This combination produces a device with the power handling capabilities of bipolar transistors, and the high input impedance and positive temperature coefficient inherent in MOS devices. Characteristic of all MOS structures, this device is free from thermal runaway and thermally-induced secondary breakdown.

Supertex's vertical DMOS FETs are ideally suited to a wide range of switching and amplifying applications where very low threshold voltage, high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

## **Ordering Information**

Device	Package Option	BV <sub>DSS</sub> /BV <sub>DGS</sub>	R <sub>DS(ON)</sub>	l <sub>D(ON)</sub> (min) (A)	
Device	TO-92	(V)	(max) (Ω)		
VN2224	VN2224N3-G	240	1.25	5.0	

-G indicates package is RoHS compliant ('Green')





## **Absolute Maximum Ratings**

Parameter	Value			
Drain-to-source voltage	BV <sub>DSS</sub>			
Drain-to-gate voltage	$BV_{DGS}$			
Gate-to-source voltage	±20V			
Operating and storage temperature	-55°C to +150°C			
Soldering temperature*	+300°C			

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.

## **Pin Configuration**



## **Product Marking**



YY = Year Sealed WW = Week Sealed \_\_\_\_ = "Green" Packaging

TO-92 (N3)

<sup>\*</sup> Distance of 1.6mm from case for 10 seconds.

### **Thermal Characteristics**

Package	l <sub>D</sub> (continuous) <sup>†</sup> (A)	I <sub>D</sub> (pulsed) (A)	Power Dissipation @T <sub>c</sub> = 25°C (W)	<b>θ</b> <sub>JC</sub> (°C/W)	θ <sub>JA</sub> (°C/W)	† (A)	I <sub>DRM</sub> (A)
TO-92	0.54	5.0	1.0	125	170	0.54	5.0

#### Notes:

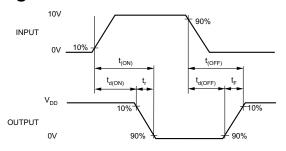
### Electrical Characteristics (T<sub>A</sub> = 25°C unless otherwise specified)

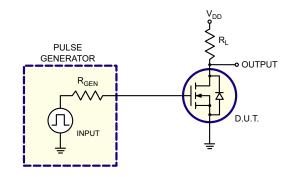
Sym	Parameter	Min	Тур	Max	Units	Conditions	
BV <sub>DSS</sub>	Drain-to-source breakdown voltage	240	-	-	V	$V_{GS} = 0V, I_{D} = 5.0 \text{mA}$	
V <sub>GS(th)</sub>	Gate threshold voltage	1.0	-	3.0	V	$V_{GS} = V_{DS}$ , $I_D = 5.0 \text{mA}$	
$\Delta V_{GS(th)}$	Change in V <sub>GS(th)</sub> with temperature	-	-4.0	-5.0	mV/°C	$V_{GS} = V_{DS}$ , $I_D = 5.0 \text{mA}$	
I <sub>GSS</sub>	Gate body leakage current	-	1.0	100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
			_	50	μA	$V_{GS} = 0V$ , $V_{DS} = Max$ Rating	
DSS	Zero gate voltage drain current	-	-	5.0	mA	$V_{DS} = 0.8$ Max Rating, $V_{GS} = 0V$ , $T_{A} = 125^{\circ}C$	
	On state drain correct	2.0	-	_		$V_{GS} = 5.0V, V_{DS} = 25V$	
I <sub>D(ON)</sub>	On-state drain current	5.0	10	-	Α	V <sub>GS</sub> = 10V, V <sub>DS</sub> = 25V	
Ь	Chatia drain to accurac an atata resistance	-	1.0	1.5	0	$V_{GS} = 5.0V, I_{D} = 2.0A$	
R <sub>DS(ON)</sub>	Static drain-to-source on-state resistance	-	0.9	1.25	Ω	V <sub>GS</sub> = 10V, I <sub>D</sub> = 2.0A	
$\Delta R_{DS(ON)}$	Change in R <sub>DS(ON)</sub> with temperature	-	1.0	1.4	%/°C	$V_{GS} = 10V, I_{D} = 2.0A$	
G <sub>FS</sub>	Forward transconductance	1000	2200	-	mmho	$V_{DS} = 25V, I_{D} = 2.0A$	
C <sub>ISS</sub>	Input capacitance	-	300	350		V <sub>GS</sub> = 0V,	
C <sub>oss</sub>	Common Source output capacitance	-	85	150	pF	$V_{DS} = 25V,$	
C <sub>RSS</sub>	Reverse transfer capacitance	-	20	35		f = 1.0MHz	
t <sub>d(ON)</sub>	Turn-on delay time	-	6.0	15			
t <sub>d(OFF)</sub>	Turn-off delay time	-	65	90	ns	$V_{DD} = 25V,$	
t <sub>r</sub>	Rise time	-	16	25		$\begin{vmatrix} I_D = 2.0A, \\ R_{GEN} = 10\Omega \end{vmatrix}$	
t <sub>f</sub>	Fall time	-	30	60		GEN	
t <sub>rr</sub>	Reverse recovery time	-	500	-	ns	V <sub>GS</sub> = 0V, I <sub>SD</sub> = 1.0A	
V <sub>SD</sub>	Diode forward voltage drop	-	0.8	1.0	V	$V_{GS} = 0V, I_{SD} = 100mA$	

#### Notes:

- 1. All D.C. parameters 100% tested at 25°C unless otherwise stated. (Pulse test: 300µs pulse, 2% duty cycle.)
- 2. All A.C. parameters sample tested.

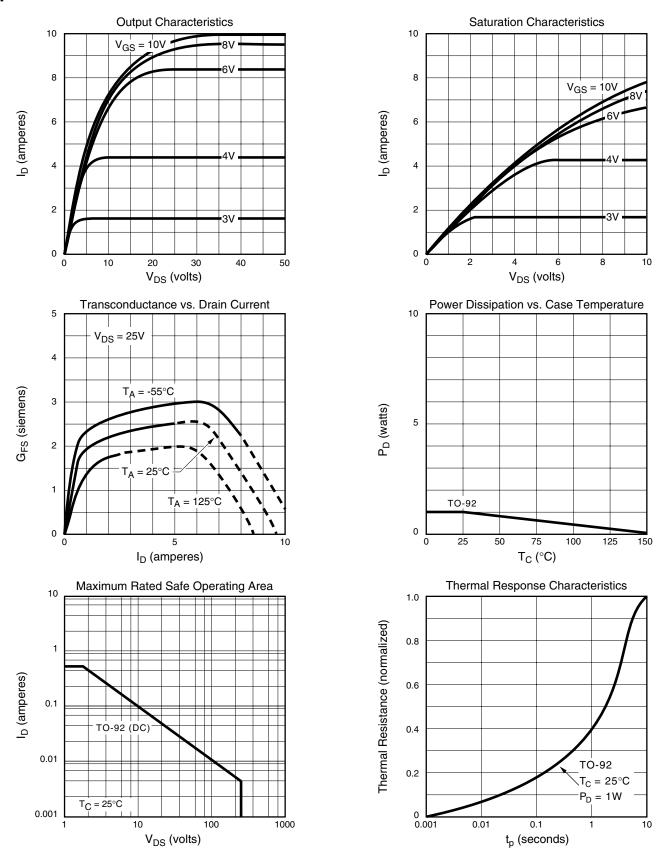
## **Switching Waveforms and Test Circuit**



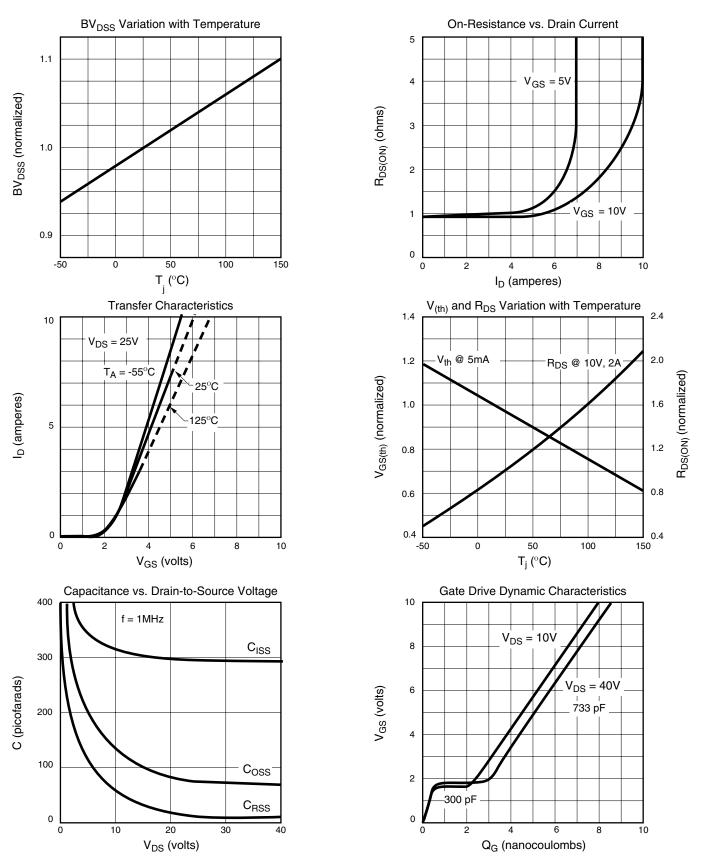


 $<sup>\</sup>dagger I_{D}$  (continuous) is limited by max rated  $T_{i}$ .

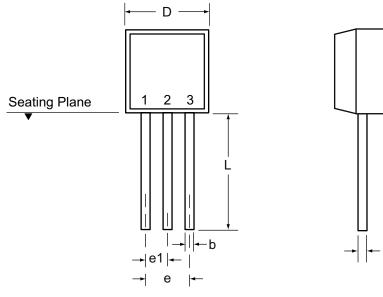
## **Typical Performance Curves**



## Typical Performance Curves (cont.)

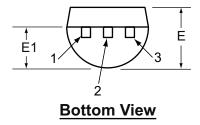


# 3-Lead TO-92 Package Outline (N3)





Side View



Sym	Symbol		b	С	D	E	E1	е	e1	L
	MIN	.170	.014	.014	.175	.125	.080	.095	.045	.500
Dimension (inches)	NOM	-	-	-	-	-	-	-	-	-
(iiiciics)	MAX	.210	.022	.022	.205	.165	.105	.105	.055	.610

Drawings not to scale.

Supertex Doc.#: DSPD-3TO92N3, Version D061608.

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <a href="http://www.supertex.com/packaging.html">http://www.supertex.com/packaging.html</a>.)

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